

Docket No. 740756-1799

## IN THE UNITED STATES ATENT AND TRADEMARK OFFICE

In re PATENT application of	)	# 22/5
Mitsunori SAKAMA	)	ANI
Serial No. 09/070,908	)	Art Unit: 1762
Filed: May 4, 1998	)	Examiner: M. Padgett
For: FILM FORMING METHOD AND	)	
FILM FORMING APPARATUS	)	
AMENDM	ENT	

Commissioner for Patents Washington, D.C. 20231

Sir:

Responsive to the Office Action dated February 15, 2001, the period for response having been extended one (1) month to June 15, 2001, the following amendments and remarks are submitted in connection with the above-identified application.

## In the claims:

Please amend the claims as follows. Attached hereto is a marked-up copy of the amended claims.

23. (Amended) A film forming method comprising the steps of:

supplying hydrogen gas into a chamber;

supplying radio frequency energy in said chamber to generate plasma from said hydrogen gas by radio frequency discharge;

supplying a reactive gas into said chamber at a same flow rate as supplying said hydrogen gas; and

forming a semiconductor film over a substrate in said chamber by decomposing said reactive gas using said radio frequency energy,

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